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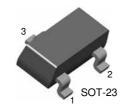




MMBT3904K

NPN Epitaxial Silicon Transistor

General Purpose Transistor





1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	60	V
V _{CEO}	Collector-Emitter Voltage	40	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current	200	mA
P _C	Collector Power Dissipation	350	mW
T _{J,} T _{STG}	Operating Junction and Storage Temperature Range	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 10 \mu A, I_E = 0$	60		V
BV _{CEO}	Collector-Emitter Breakdown Voltage *	$I_{C} = 1 \text{ mA}, I_{B} = 0$	40		V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	6		V
I _{CEX}	Collector Cut-off Current	V _{CE} = 30V, V _{EB} = 3V		50	nA
h _{FE}	DC Current Gain *	$V_{CE} = 1V$, $I_{C} = 0.1$ mA $V_{CE} = 1V$, $I_{C} = 1$ mA $V_{CE} = 1V$, $I_{C} = 10$ mA $V_{CE} = 1V$, $I_{C} = 50$ mA $V_{CE} = 1V$, $I_{C} = 100$ mA	40 70 100 60 30	300	
V _{CE} (sat)	Collector-Emitter Saturation Voltage *	I _C = 10mA, I _B = 1mA I _C = 50mA, I _B = 5mA		0.2 0.3	V V
V _{BE} (sat)	Base-Emitter Saturation Voltage *	I _C = 10mA, I _B = 1mA I _C = 50mA, I _B = 5mA	0.65	0.85 0.95	V V
C _{ob}	Output Capacitance	$V_{CB} = 5V, I_{E} = 0, f = 1MHz$		4	pF
f _T	Current Gain-Bandwidth Product	V _{CE} = 20V, I _C = 10mA, f = 100MHz	300		MHz
NF	Noise Figure	$I_C = 100\mu A, V_{CE} = 5V, R_S = 1K\Omega$ f = 10Hz to 15.7KHz		5	dB
t _{ON}	Turn On Time	V _{CC} = 3V, V _{BE} = 0.5V I _C = 10mA, I _{B1} = 1mA		70	ns
t _{OFF}	Turn Off Time	$V_{CC} = 3V, I_C = 10mA, I_{B1} = I_{B2} = 1mA$		250	ns

^{*} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%

Typical Performance Characteristics

Figure 1. DC current Gain

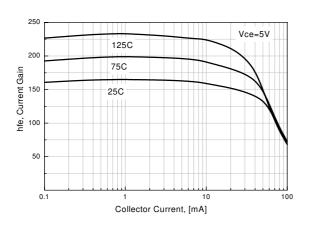


Figure 2. Collector-Emitter Saturation Voltage

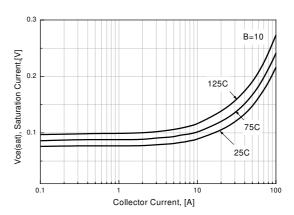


Figure 3. Base-Emitter Saturation Voltage

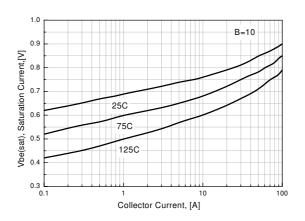


Figure 4. Collector - Base Leakage Current

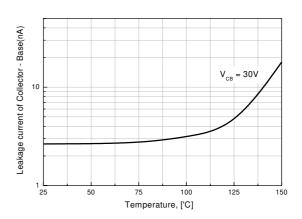


Figure 5. Output Capacitance

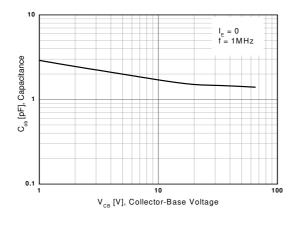
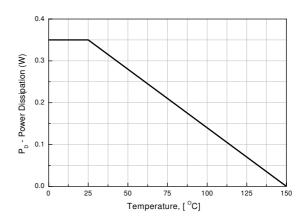
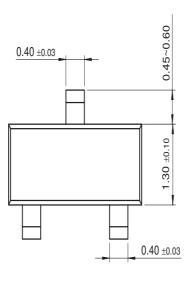


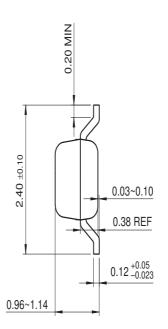
Figure 6. Power Dissipation vs
Ambient Temperature

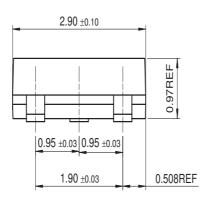


Mechanical Dimensions

SOT-23







Dimensions in Millimeters

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